



DMNH6012LK3

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C
60V	$12m\Omega @ V_{GS} = 10V$	60A
000	18mΩ @ V <sub>GS</sub> = 4.5V	50A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101 and ideal for use in:

- Body Control Electronics
- DC/DC Converters

### Features

Rated to +175°C - Ideal for High Ambient Temperature Environments

60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

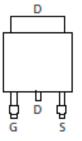
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

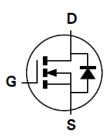
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@)
- Weight: 0.33 grams (Approximate)



Top View



Pin Out Top View



Equivalent Circuit

## Ordering Information (Note 4)

Part Number	Case	Packaging
DMNH6012LK3-13	TO252	2500/Tape & Reel

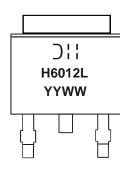
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



) | | =Manufacturer's Marking H6012L = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 15 = 2015) WW = Week Code (01 to 53)



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I <sub>D</sub>	60 40	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	120	А	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	2.6	А	
Avalanche Current, L = 0.1mH (Note 7)		I <sub>AS</sub>	45	A
Avalanche Energy, L = 0.1mH (Note 7)	Eas	100	mJ	

Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	2.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	$R_{\theta JA}$	74	°C/W	
Total Power Dissipation (Note 6)		PD	3.8	W	
Thermal Resistance, Junction to Ambient (Note 6) Steady state		$R_{\thetaJA}$	40	°C/W	
Thermal Resistance, Junction to Case		R <sub>θ</sub> JC	1.2	C/VV	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C		

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			I				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			-			-	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current, T <sub>J</sub> = +25°C	I <sub>DSS</sub>		_	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			8	12	mΩ	$V_{GS} = 10V, I_D = 25A$	
	R <sub>DS(ON)</sub>	_	10	18	11122	$V_{GS} = 4.5V, I_D = 25A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.7A$	
DYNAMIC CHARACTERISTICS (Note 9)	<u>.</u>						
Input Capacitance	C <sub>iss</sub>	_	1926	—	pF		
Output Capacitance	Coss		330	_	pF	−V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, −f = 1MHz	
Reverse Transfer Capacitance	Crss		112	_	pF		
Gate Resistance	Rg	-	2.0	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		16.3	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	35.2	—	nC	Vps = 30V. lp = 25A	
Gate-Source Charge	Q <sub>gs</sub>	_	7.6	—	nC	$v_{DS} = 30v, I_D = 25A$	
Gate-Drain Charge	Q <sub>gd</sub>	-	6.9	_	nC	7	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.4	_	ns		
Turn-On Rise Time	t <sub>R</sub>	—	11.9	—	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	16.5	_	ns	$R_{G} = 3\Omega, I_{D} = 25A$	
Turn-Off Fall Time	t <sub>F</sub>		5	_	ns		
Body Diode Reverse Recovery Time	t <sub>RR</sub>		28	_	ns	I <sub>F</sub> = 25A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		23	_	nC	$T_{F} = 25A, a/at = 100A/\mu s$	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

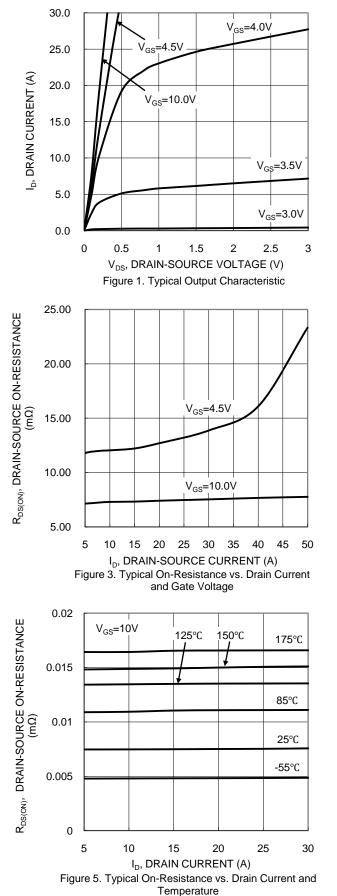
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

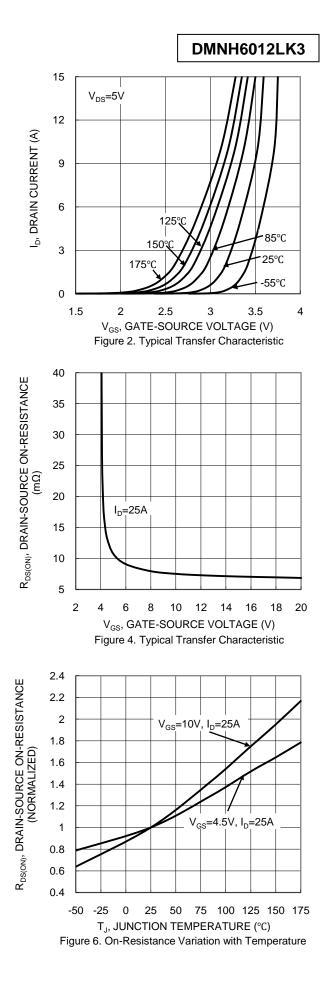
7.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

Notes:

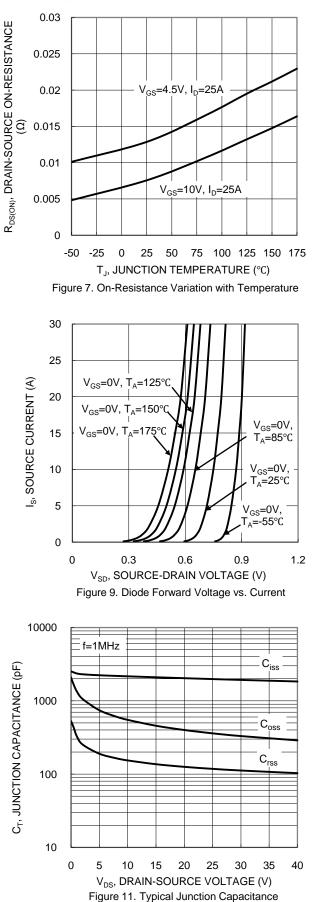


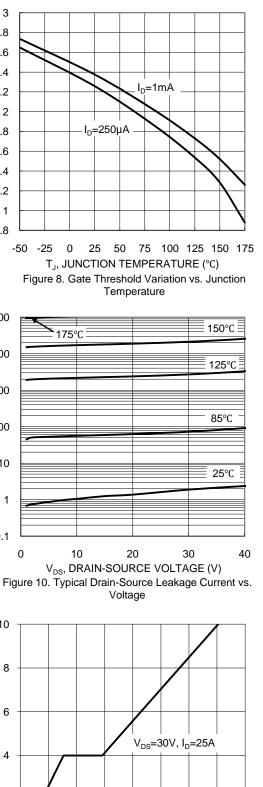




NEW PRODUCT







DMNH6012LK3

3

2.8

2.6 2.4

2.2 2

1.8 1.6

1.4

1.2

1

0.8

100000

10000

1000

100

10

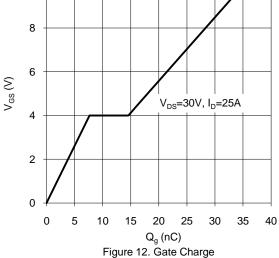
1

0.1

10

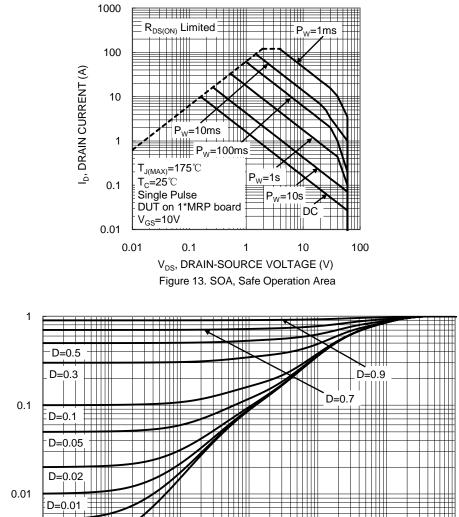
I<sub>DSS</sub>, LEAKAGE CURRENT (nA)

 $V_{\text{GS}(\text{TH})},$  GATE THRESHOLD VOLTAGE (V)



NEW PRODUCT

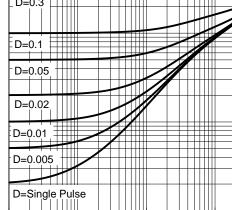






0.001

0.001



0.01

0.1 1 10 t1, PULSE DURATION TIME (sec) Figure 14. Transient Thermal Resistance

 $R_{\theta JA}(t)=r(t) * R_{\theta JA}$ R<sub>θJA</sub>=73.5℃/W

Duty Cycle, D=t1 / t2

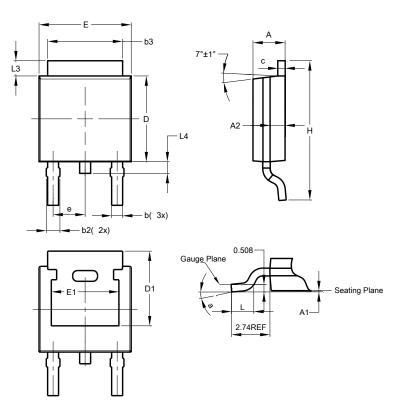
100

1000



# **Package Outline Dimensions**

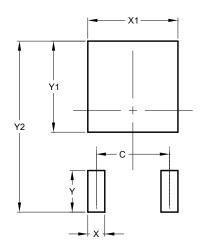
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Ε	6.45	6.70	6.58			
E1	4.32	-	-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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